HERAF801G – HERAF808G

Taiwan Semiconductor

8A, 50V - 1000V High Efficient Rectifier

FEATURES

- AEC-Q101 qualified available
- Glass passivated chip junction
- High efficiency, Low V_F
- High current capability
- High reliability
- High surge current capability
- UL Recognized File # E-326243
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- DC to DC converter
- Switching mode converters and inverters
- Freewheeling application

MECHANICAL DATA

- Case: ITO-220AC
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Mounting torque: 0.56 N·m maximum
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 1.70g (approximately)

KEY PARAMETERS				
PARAMETER	VALUE	UNIT		
I _F	8	А		
V _{RRM}	50 - 1000	V		
I _{FSM}	150	А		
T _{J MAX}	150	°C		
Package	ITO-220AC			
Configuration	Single die			





PIN 2 O-

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$ unless otherwise noted)										
PARAMETER	SYMBOL	HERAF 801G	HERAF 802G	HERAF 803G	HERAF 804G	HERAF 805G	HERAF 806G	HERAF 807G	HERAF 808G	UNIT
Marking code on the device		HERAF 801G	HERAF 802G	HERAF 803G	HERAF 804G	HERAF 805G	HERAF 806G	HERAF 807G	HERAF 808G	
Repetitive peak reverse voltage	V _{RRM}	50	100	200	300	400	600	800	1000	V
Reverse voltage total rms value	V _{R(RMS)}	35	70	140	210	280	420	560	700	V
Forward current	١ _F		8					А		
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I _{FSM}	150					A			
Junction temperature	TJ	-55 to +150					°C			
Storage temperature	T _{STG}	-55 to +150				°C				



THERMAL PERFORMANCE			
PARAMETER	SYMBOL	ТҮР	UNIT
Junction-to-case resistance	R _{eJC}	2	°C/W

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
	HERAF801G HERAF802G HERAF803G HERAF804G			-	1.0	V
Forward voltage ⁽¹⁾	HERAF805G	I _F = 8A, T _J = 25°C	V _F	-	1.3	V
	HERAF806G HERAF807G HERAF808G			-	1.7	V
	(2)	$T_J = 25^{\circ}C$		-	10	μA
Reverse current @ rated $V_R^{(2)}$		T _J = 125°C	I _R	-	400	μA
lunction capacitance	HERAF801G HERAF802G HERAF803G HERAF804G HERAF805G	1MHz, V _R = 4.0V	CJ	80	-	pF
	HERAF806G HERAF807G HERAF808G			60	-	pF
Reverse recovery time	HERAF801G HERAF802G HERAF803G HERAF804G HERAF805G	IF = 0.5A, IR = 1.0A Irr = 0.25A	t _{rr}	-	50	ns
	HERAF806G HERAF807G HERAF808G			-	80	ns

Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

ORDERING INFORMATION		
ORDERING CODE ⁽¹⁾⁽²⁾	PACKAGE	PACKING
HERAF8xG	ITO-220AC	50 / Tube
HERAF8xGH	ITO-220AC	50 / Tube

Notes:

1. "x" defines voltage from 50V(HERAF801G) to 1000V(HERAF808G)

2. "H" means AEC-Q101 qualified



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CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

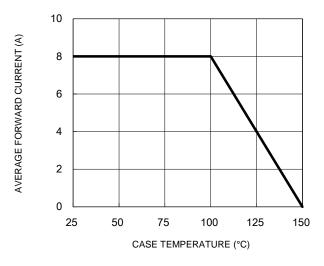


Fig.1 Forward Current Derating Curve

Fig.3 Typical Reverse Characteristics

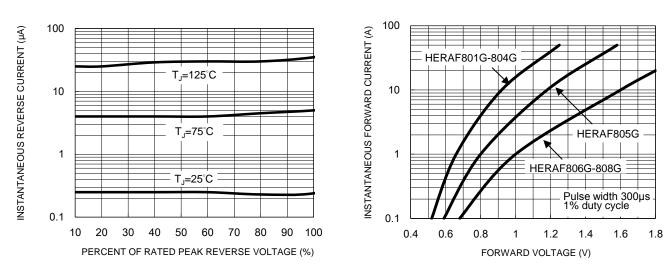


Fig.5 Maximum Non-Repetitive Forward Surge Current

1000

100

10

1

1

f=1.0MHz Vsig=50mVp-p

CAPACITANCE (pF)

Fig.2 Typical Junction Capacitance

HERAF801G-805G

10

REVERSE VOLTAGE (V)

Fig.4 Typical Forward Characteristics

100

HERAF806G-808G



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CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

50Ω 10Ω - trr 🗕 NONINDUCTIVE NONINDUCTIVE ~~~ ~~~ +0.5A (-) ± DUT • (+) 50Vdc PULSE 0 GENERATOR = (approx) -0.25A (NOTE 2) (-) IΩ OSCILLOSCOPE 6 (+) (NOTE 1) -1.0A NOTES: 1. Rise Time=7ns max. Input Impedance= ≐ 1 megohm 22pf 2. Rise Time=10ns max. Sourse Impedance= 50 ohms

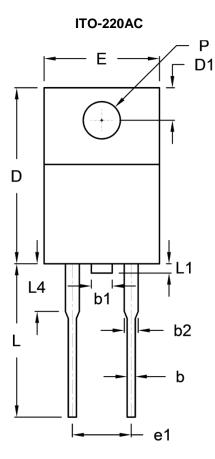
Fig.6 Reverse Recovery Time Characteristic and Test Circuit Diagram

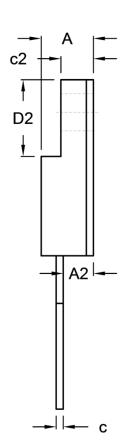


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PACKAGE OUTLINE DIMENSIONS





DIM. Unit (mm)		Unit	(inch)	
	Min.	Max.	Min.	Max.
A	4.30	4.70	0.169	0.185
A2	2.30	2.90	0.091	0.114
b	0.50	0.90	0.020	0.035
b1	-	1.80	-	0.071
b2	0.95	1.45	0.037	0.057
с	0.46	0.76	0.018	0.030
c2	2.50	3.10	0.098	0.114
D	14.80	15.50	0.583	0.610
D1	2.40	3.20	0.094	0.126
D2	6.30	6.90	0.248	0.272
E	9.60	10.30	0.378	0.406
e1	4.95	5.20	0.195	0.205
L	12.60	13.80	0.496	0.543
L1	0.00	1.60	0.000	0.063
L4	-	4.10	-	0.161
Р	3.00	3.40	0.118	0.134

MARKING DIAGRAM



P/N	= Marking Code
G	= Green Compound
YWW	= Date Code
F	= Factory Code



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